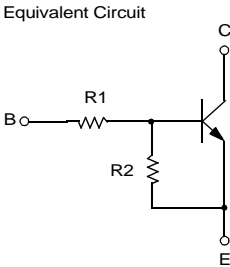
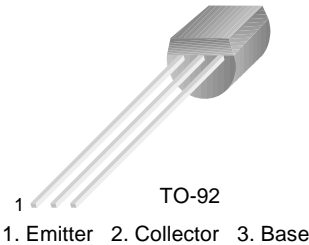




KSR1001

Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor ($R_1=4.7K\Omega$, $R_2=4.7K\Omega$)
- Complement to KSR2001



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	10	V
I_C	Collector Current	100	mA
P_C	Collector Power Dissipation	300	mW
T_J	Junction Temperature	150	$^{\circ}C$
T_{STG}	Storage Temperature	-55 ~ 150	$^{\circ}C$

Electrical Characteristics $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C=10\mu A$, $I_E=0$	50			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=100\mu A$, $I_B=0$	50			V
I_{CBO}	Collector Cut-off Current	$V_{CB}=40V$, $I_E=0$			0.1	μA
h_{FE}	DC Current Gain	$V_{CE}=5V$, $I_C=10mA$	20			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=10mA$, $I_B=0.5mA$			0.3	V
f_T	Current Gain Bandwidth Product	$V_{CE}=10V$, $I_C=5mA$		250		MHz
C_{ob}	Output Capacitance	$V_{CB}=10V$, $I_E=0$ $f=1.0MHz$		3.7		pF
$V_I(off)$	Input Off Voltage	$V_{CE}=5V$, $I_C=100\mu A$	0.5			V
$V_I(on)$	Input On Voltage	$V_{CE}=0.3V$, $I_C=20mA$			3	V
R_1	Input Resistor		3.2	4.7	6.2	$K\Omega$
R_1/R_2	Resistor Ratio		0.9	1	1.1	

Typical Characteristics

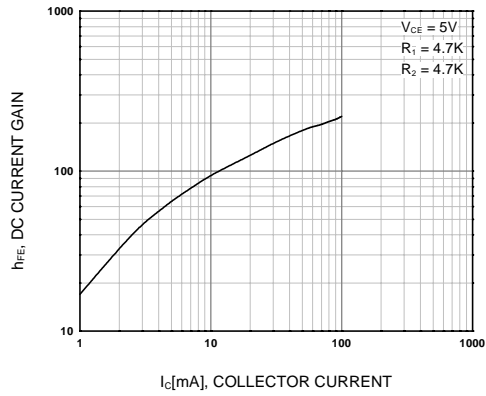


Figure 1. DC current Gain

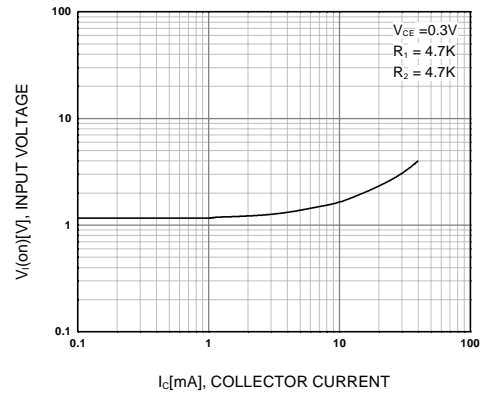


Figure 2. Input On Voltage

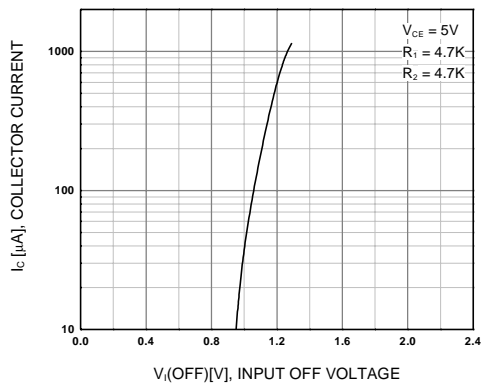


Figure 3. Input Off Voltage

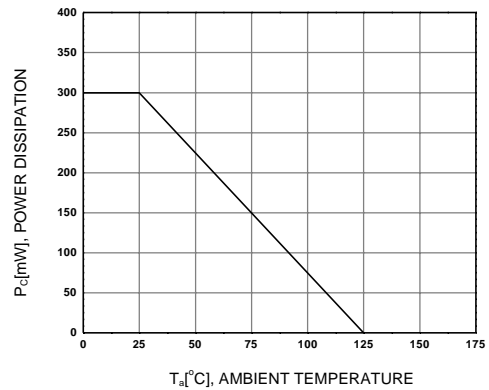


Figure 4. Power Derating

Package Dimensions

TO-92



Dimensions in Millimeters

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